

10MHz, 6V/ μ s, Dual/Quad Rail-to-Rail Input and Output Precision C-Load Op Amps

FEATURES

- Rail-to-Rail Input and Output
- 475 μ V Max V_{OS} from V^+ to V^-
- Gain-Bandwidth Product: 10MHz
- Slew Rate: 6V/ μ s
- Low Supply Current per Amplifier: 1.7mA
- Input Offset Current: 65nA Max
- Input Bias Current: 650nA Max
- Open-Loop Gain: 1000V/mV Min
- Low Input Noise Voltage: 12nV/ $\sqrt{\text{Hz}}$ Typ
- Wide Supply Range: 2.2V to ± 15 V
- Large Output Drive Current: 30mA
- Stable for Capacitive Loads Up to 10,000pF
- Dual in 8-Pin PDIP and SO Package
- Quad in Narrow 14-Pin SO

APPLICATIONS

- Driving A-to-D Converters
- Active Filters
- Rail-to-Rail Buffer Amplifiers
- Low Voltage Signal Processing
- Battery-Powered Systems

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DESCRIPTION

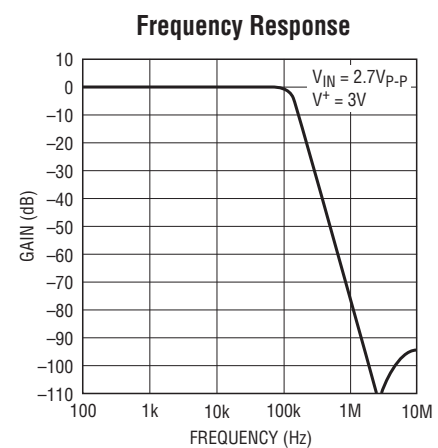
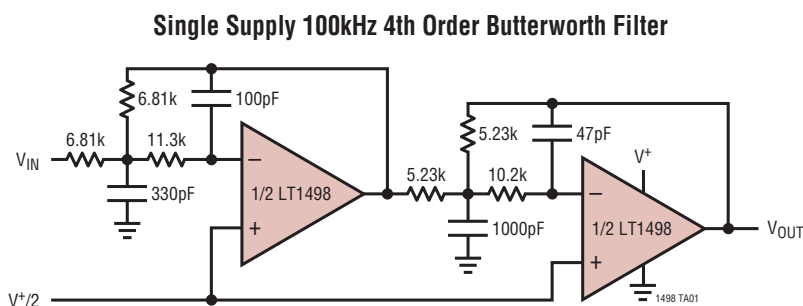
The LT[®]1498/LT1499 are dual/quad, rail-to-rail input and output precision C-Load[™] op amps with a 10MHz gain-bandwidth product and a 6V/ μ s slew rate.

The LT1498/LT1499 are designed to maximize input dynamic range by delivering precision performance over the full supply voltage. Using a patented technique, both input stages of the LT1498/LT1499 are trimmed, one at the negative supply and the other at the positive supply. The resulting guaranteed common mode rejection is much better than other rail-to-rail input op amps. When used as a unity-gain buffer in front of single supply 12-bit A-to-D converters, the LT1498/LT1499 are guaranteed to add less than 1LSB of error even in single 3V supply systems.

With 110dB of supply rejection, the LT1498/LT1499 maintain their performance over a supply range of 2.2V to 36V and are specified for 3V, 5V and ± 15 V supplies. The inputs can be driven beyond the supplies without damage or phase reversal of the output. These op amps remain stable while driving capacitive loads up to 10,000pF.

The LT1498 is available with the standard dual op amp configuration in 8-pin PDIP and SO packaging. The LT1499 features the standard quad op amp configuration and is available in a 14-pin plastic SO package. These devices can be used as plug-in replacements for many standard op amps to improve input/output range and precision.

TYPICAL APPLICATION

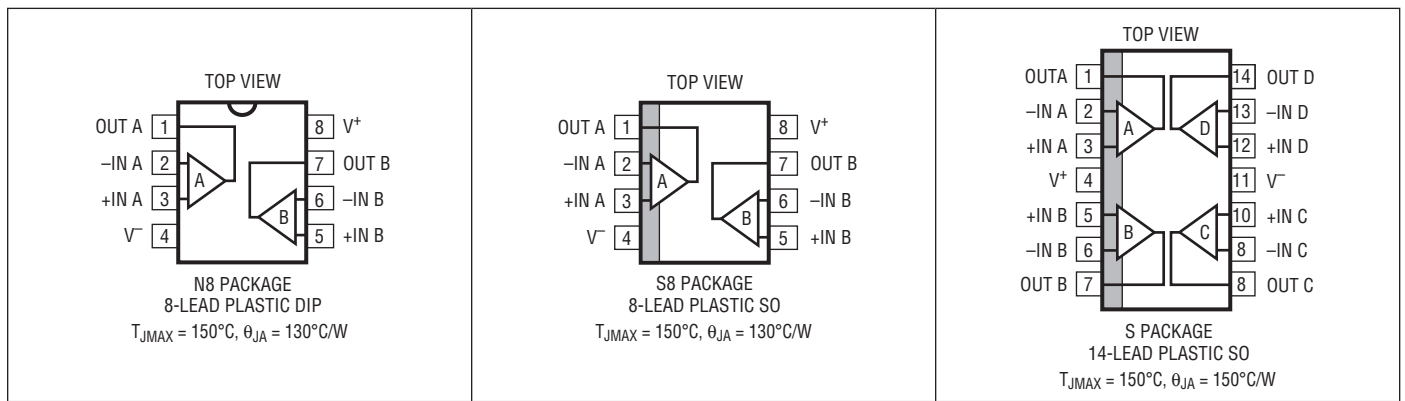


LT1498/LT1499

ABSOLUTE MAXIMUM RATINGS (Note 1)

| | | | |
|--|--|---|--|
| Total Supply Voltage (V^+ to V^-)..... | 36V | Specified Temperature Range (Note 4) | |
| Input Current..... | $\pm 10\text{mA}$ | LT1498/LT1499..... | -40°C to 85°C |
| Output Short-Circuit Duration (Note 2)..... | Continuous | LT1498H/LT1499H..... | -40°C to 125°C |
| Operating Temperature Range | | LT1498MP..... | -55°C to 125°C |
| LT1498/LT1499..... | -40°C to 85°C | Junction Temperature..... | 150°C |
| LT1498H/LT1499H..... | -40°C to 125°C | Storage Temperature Range..... | -65°C to 150°C |
| LT1498MP..... | -55°C to 125°C | Lead Temperature (Soldering, 10 sec)..... | 300°C |

PIN CONFIGURATION



ORDER INFORMATION

| LEAD FREE FINISH | TAPE AND REEL | PART MARKING* | PACKAGE DESCRIPTION | SPECIFIED TEMPERATURE RANGE |
|------------------|------------------|---------------|---------------------|--|
| LT1498CN8#PBF | LT1498CN8#TRPBF | LT1498CN8 | 8-Lead Plastic PDIP | 0°C to 70°C |
| LT1498CS8#PBF | LT1498CS8#TRPBF | 1498 | 8-Lead Plastic SO | 0°C to 70°C |
| LT1498IN8#PBF | LT1498IN8#TRPBF | LT1498IN8 | 8-Lead Plastic PDIP | -40°C to 85°C |
| LT1498IS8#PBF | LT1498IS8#TRPBF | 1498I | 8-Lead Plastic SO | -40°C to 85°C |
| LT1498HS8#PBF | LT1498HS8#TRPBF | 1498H | 8-Lead Plastic SO | -40°C to 125°C |
| LT1498MPS8#PBF | LT1498MPS8#TRPBF | 1498MP | 8-Lead Plastic SO | -55°C to 125°C |
| LT1499CS#PBF | LT1499CS#TRPBF | LT1499CS | 14-Lead Plastic SO | 0°C to 70°C |
| LT1499IS#PBF | LT1499IS#TRPBF | LT1499IS | 14-Lead Plastic SO | -40°C to 85°C |
| LT1499HS#PBF | LT1499HS#TRPBF | LT1499HS | 14-Lead Plastic SO | -40°C to 125°C |

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>
For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandree/>

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_{OUT} = \text{half supply}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|---|--|--|-----------|----------|------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | | 150 | 475 | μV |
| | | $V_{CM} = V^-$ | | 150 | 475 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^- \text{ to } V^+$ | | 150 | 425 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{CM} = V^+, V^-$ (Note 5) | | 200 | 750 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | 0 | 250 | 650 | nA |
| | | $V_{CM} = V^-$ | -650 | -250 | 0 | nA |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^- \text{ to } V^+$ | | 500 | 1300 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{CM} = V^+$ (Note 5) $V_{CM} = V^-$ (Note 5) | 0 -100 | 10 -10 | 100 0 | nA nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | | 5 | 65 | nA |
| | | $V_{CM} = V^-$ | | 5 | 65 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^- \text{ to } V^+$ | | 10 | 130 | nA |
| | Input Noise Voltage | 0.1Hz to 10Hz | | 400 | | nV _{p-p} |
| e_n | Input Noise Voltage Density | $f = 1\text{kHz}$ | | 12 | | nV/ $\sqrt{\text{Hz}}$ |
| i_n | Input Noise Current Density | $f = 1\text{kHz}$ | | 0.3 | | pA/ $\sqrt{\text{Hz}}$ |
| C_{IN} | Input Capacitance | | | 5 | | pF |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}$, $V_O = 75\text{mV to } 4.8\text{V}$, $R_L = 10\text{k}$ | 600 | 3800 | | V/mV |
| | | $V_S = 3\text{V}$, $V_O = 75\text{mV to } 2.8\text{V}$, $R_L = 10\text{k}$ | 500 | 2000 | | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}$, $V_{CM} = V^- \text{ to } V^+$ | 81 | 90 | | dB |
| | | $V_S = 3\text{V}$, $V_{CM} = V^- \text{ to } V^+$ | 76 | 86 | | dB |
| | | CMRR Match (Channel-to-Channel) (Note 5) | $V_S = 5\text{V}$, $V_{CM} = V^- \text{ to } V^+$ $V_S = 3\text{V}$, $V_{CM} = V^- \text{ to } V^+$ | 75 70 | 91 86 | |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.2\text{V to } 12\text{V}$, $V_{CM} = V_O = 0.5\text{V}$ | 88 | 105 | | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = 2.2\text{V to } 12\text{V}$, $V_{CM} = V_O = 0.5\text{V}$ | 82 | 103 | | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | | 14 | 30 | mV |
| | | $I_{SINK} = 0.5\text{mA}$ | | 35 | 70 | mV |
| | | $I_{SINK} = 2.5\text{mA}$ | | 90 | 200 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | | 2.5 | 10 | mV |
| | | $I_{SOURCE} = 0.5\text{mA}$ | | 50 | 100 | mV |
| | | $I_{SOURCE} = 2.5\text{mA}$ | | 140 | 250 | mV |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ | ± 12.5 | ± 24 | | mA |
| | | $V_S = 3\text{V}$ | ± 12.0 | ± 19 | | mA |
| I_S | Supply Current per Amplifier | | | 1.7 | 2.2 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | 6.8 | 10.5 | | MHz |
| SR | Slew Rate (Note 8) | $V_S = 5\text{V}$, $A_V = -1$, $R_L = \text{Open}$, $V_O = 4\text{V}$ | 2.6 | 4.5 | | V/ μs |
| | | $V_S = 3\text{V}$, $A_V = -1$, $R_L = \text{Open}$ | 2.3 | 4.0 | | V/ μs |

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range 0°C < T_A < 70°C. V_S = 5V, 0V; V_S = 3V, 0V; V_{CM} = V_{OUT} = half supply, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------|---|--|--------|-----------|-----------|----------|
| V _{OS} | Input Offset Voltage | V _{CM} = V ⁺ | ● | 175 | 650 | μV |
| | | V _{CM} = V ⁻ + 0.1V | ● | 175 | 650 | μV |
| V _{OS} TC | Input Offset Voltage Drift (Note 3) | V _{CM} = V ⁺ | ● | 0.5 | 2.5 | μV/°C |
| | | V _{CM} = V ⁻ + 0.1V | ● | 1.5 | 4.0 | μV/°C |
| ΔV _{OS} | Input Offset Voltage Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 170 | 600 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | V _{CM} = V ⁻ + 0.1V, V ⁺ (Note 5) | ● | 200 | 900 | μV |
| I _B | Input Bias Current | V _{CM} = V ⁺ | ● | 0 | 275 | nA |
| | | V _{CM} = V ⁻ + 0.1V | ● | -780 | -275 | 0 |
| ΔI _B | Input Bias Current Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 550 | 1560 | nA |
| | Input Bias Current Match (Channel-to-Channel) | V _{CM} = V ⁺ (Note 5) V _{CM} = V ⁻ + 0.1V (Note 5) | ● ● | 0 -170 | 15 -15 | 170 0 |
| I _{OS} | Input Offset Current | V _{CM} = V ⁺ | ● | 10 | 85 | nA |
| | | V _{CM} = V ⁻ + 0.1V | ● | 10 | 85 | nA |
| ΔI _{OS} | Input Offset Current Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 20 | 170 | nA |
| A _{VOL} | Large-Signal Voltage Gain | V _S = 5V, V _O = 75mV to 4.8V, R _L = 10k | ● | 500 | 2500 | V/mV |
| | | V _S = 3V, V _O = 75mV to 2.8V, R _L = 10k | ● | 400 | 2000 | V/mV |
| CMRR | Common Mode Rejection Ratio | V _S = 5V, V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 78 | 89 | dB |
| | | V _S = 3V, V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 73 | 85 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | V _S = 5V, V _{CM} = V ⁻ + 0.1V to V ⁺ V _S = 3V, V _{CM} = V ⁻ + 0.1V to V ⁺ | ● ● | 74 69 | 90 86 | dB dB |
| PSRR | Power Supply Rejection Ratio | V _S = 2.3V to 12V, V _{CM} = V _O = 0.5V | ● | 86 | 102 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | V _S = 2.3V to 12V, V _{CM} = V _O = 0.5V | ● | 80 | 102 | dB |
| V _{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 17 | 35 | mV |
| | | I _{SINK} = 0.5mA | ● | 40 | 80 | mV |
| | | I _{SINK} = 2.5mA | ● | 110 | 220 | mV |
| V _{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 15 | mV |
| | | I _{SOURCE} = 0.5mA | ● | 55 | 120 | mV |
| | | I _{SOURCE} = 2.5mA | ● | 160 | 300 | mV |
| I _{SC} | Short-Circuit Current | V _S = 5V | ● | ±12 | ±23 | mA |
| | | V _S = 3V | ● | ±10 | ±20 | mA |
| I _S | Supply Current per Amplifier | | ● | 1.9 | 2.6 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 6.1 | 9 | MHz |
| SR | Slew Rate (Note 8) | V _S = 5V, A _V = -1, R _L = Open, V _O = 4V | ● | 2.5 | 4.0 | V/μs |
| | | V _S = 3V, A _V = -1, R _L = Open | ● | 2.2 | 3.5 | V/μs |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the temperature range $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$. $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{\text{CM}} = V_{\text{OUT}} = \text{half supply}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------|---|--|--------|-----------|-----------|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{\text{CM}} = V^+$ | ● | 250 | 750 | μV |
| | | $V_{\text{CM}} = V^- + 0.1\text{V}$ | ● | 250 | 750 | μV |
| $V_{\text{OS TC}}$ | Input Offset Voltage Drift (Note 3) | $V_{\text{CM}} = V^+$ | ● | 0.5 | 2.5 | $\mu\text{V}/^{\circ}\text{C}$ |
| | | $V_{\text{CM}} = V^- + 0.1\text{V}$ | ● | 1.5 | 4.0 | $\mu\text{V}/^{\circ}\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● | 250 | 650 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{\text{CM}} = V^- + 0.1\text{V}, V^+$ (Note 5) | ● | 300 | 1500 | μV |
| I_B | Input Bias Current | $V_{\text{CM}} = V^+$ | ● | 0 | 350 | nA |
| | | $V_{\text{CM}} = V^- + 0.1\text{V}$ | ● | -975 | -350 | 0 |
| ΔI_B | Input Bias Current Shift | $V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● | 700 | 1950 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{\text{CM}} = V^+$ (Note 5) $V_{\text{CM}} = V^- + 0.1\text{V}$ (Note 5) | ● ● | 0 -180 | 30 -30 | 180 0 |
| I_{OS} | Input Offset Current | $V_{\text{CM}} = V^+$ | ● | 15 | 110 | nA |
| | | $V_{\text{CM}} = V^- + 0.1\text{V}$ | ● | 15 | 110 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● | 30 | 220 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}, V_O = 75\text{mV}$ to $4.8\text{V}, R_L = 10\text{k}$ | ● | 400 | 2500 | V/mV |
| | | $V_S = 3\text{V}, V_O = 75\text{mV}$ to $2.8\text{V}, R_L = 10\text{k}$ | ● | 300 | 2000 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}, V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● | 77 | 86 | dB |
| | | $V_S = 3\text{V}, V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● | 73 | 81 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_S = 5\text{V}, V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ $V_S = 3\text{V}, V_{\text{CM}} = V^- + 0.1\text{V}$ to V^+ | ● ● | 72 69 | 86 83 | dB dB |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.5\text{V}$ to $12\text{V}, V_{\text{CM}} = V_O = 0.5\text{V}$ | ● | 86 | 100 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = 2.5\text{V}$ to $12\text{V}, V_{\text{CM}} = V_O = 0.5\text{V}$ | ● | 80 | 100 | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 18 | 40 | mV |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | 45 | 80 | mV |
| | | $I_{\text{SINK}} = 2.5\text{mA}$ | ● | 110 | 220 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 15 | mV |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | 60 | 120 | mV |
| | | $I_{\text{SOURCE}} = 2.5\text{mA}$ | ● | 170 | 300 | mV |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ | ● | ± 7.5 | ± 15 | mA |
| | | $V_S = 3\text{V}$ | ● | ± 7.5 | ± 15 | mA |
| I_S | Supply Current per Amplifier | | ● | 2.0 | 2.7 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz |
| SR | Slew Rate (Note 8) | $V_S = 5\text{V}, A_V = -1, R_L = \text{Open}, V_O = 4\text{V}$ | ● | 2.2 | 3.6 | V/ μs |
| | | $V_S = 3\text{V}, A_V = -1, R_L = \text{Open}$ | ● | 1.9 | 3.2 | V/ μs |

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$. $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{CM} = V_{OUT} = \text{half supply}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS | |
|-----------------|---|--|--------|-----------|-----------|--------------------------------|----------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 300 | 1100 | μV | |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | 300 | 1100 | μV | |
| $V_{OS\ TC}$ | Input Offset Voltage Drift (Note 3) | | ● | 0.5 | | $\mu\text{V}/^{\circ}\text{C}$ | |
| | | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 1.5 | | $\mu\text{V}/^{\circ}\text{C}$ | |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 250 | 2300 | μV | |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{CM} = V^- + 0.5\text{V}, V^+ - 0.5\text{V}$ (Note 5) | ● | 300 | 1900 | μV | |
| I_B | Input Bias Current | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 0 | 450 | nA | |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | -1100 | -450 | 0 | |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 900 | 2200 | nA | |
| | Input Bias Current Match (Channel-to-Channel) | $V_{CM} = V^+ - 0.5\text{V}$ (Note 5) $V_{CM} = V^- + 0.5\text{V}$ (Note 5) | ● ● | 0 -400 | 40 -40 | 400 0 | nA nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 40 | 300 | nA | |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | 40 | 300 | nA | |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 600 | nA | |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}, V_O = 0.5\text{V}$ to $4.5\text{V}, R_L = 10\text{k}$ | ● | 40 | 210 | V/mV | |
| | | $V_S = 3\text{V}, V_O = 0.5\text{V}$ to $2.5\text{V}, R_L = 10\text{k}$ | ● | 20 | 210 | V/mV | |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}, V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ $V_S = 3\text{V}, V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● ● | 66 62 | 80 75 | dB dB | |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_S = 5\text{V}, V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ $V_S = 3\text{V}, V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● ● | 62 58 | 80 75 | dB dB | |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.5\text{V}$ to $12\text{V}, V_{CM} = V_O = 0.5\text{V}$ | ● | 86 | 100 | dB | |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = 2.5\text{V}$ to $12\text{V}, V_{CM} = V_O = 0.5\text{V}$ | ● | 80 | 100 | dB | |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | | 22 | 50 | mV |
| | | $I_{SINK} = 0.5\text{mA}$ | ● | | 45 | 80 | mV |
| | | $I_{SINK} = 2.5\text{mA}$ | ● | | 110 | 220 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | | 3.5 | 20 | mV |
| | | $I_{SOURCE} = 0.5\text{mA}$ | ● | | 60 | 120 | mV |
| | | $I_{SOURCE} = 2.5\text{mA}$ | ● | | 170 | 350 | mV |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ | ● | ± 5 | ± 15 | mA | |
| | | $V_S = 3\text{V}$ | ● | ± 5 | ± 15 | mA | |
| I_S | Supply Current per Amplifier | | ● | 2.4 | 3.0 | mA | |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz | |
| SR | Slew Rate (Note 8) | $V_S = 5\text{V}, A_V = -1, R_L = \text{Open}, V_O = 4\text{V}$ | ● | 2.0 | 3.6 | V/ μs | |
| | | $V_S = 3\text{V}, A_V = -1, R_L = \text{Open}$ | ● | 1.7 | 3.2 | V/ μs | |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the temperature range $-55^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$. $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{\text{CM}} = V_{\text{OUT}} = \text{half supply}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------|---|--|--------|-----------|----------|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 300 | 1100 | μV |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | 300 | 1100 | μV |
| $V_{\text{OS TC}}$ | Input Offset Voltage Drift (Note 3) | | ● | 0.5 | | $\mu\text{V}/^{\circ}\text{C}$ |
| | | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 1.5 | | $\mu\text{V}/^{\circ}\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 250 | 2300 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{\text{CM}} = V^- + 0.5\text{V}, V^+ - 0.5\text{V}$ (Note 5) | ● | 300 | 1900 | μV |
| I_B | Input Bias Current | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 0 | 1100 | nA |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | -1100 | 0 | nA |
| ΔI_B | Input Bias Current Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 900 | 2200 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{\text{CM}} = V^+ - 0.5\text{V}$ (Note 5) $V_{\text{CM}} = V^- + 0.5\text{V}$ (Note 5) | ● ● | 0 -400 | 400 0 | nA nA |
| I_{OS} | Input Offset Current | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 40 | 300 | nA |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | 40 | 300 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 600 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}, V_O = 0.5\text{V}$ to $4.5\text{V}, R_L = 10\text{k}$ | ● | 40 | 210 | V/mV |
| | | $V_S = 3\text{V}, V_O = 0.5\text{V}$ to $2.5\text{V}, R_L = 10\text{k}$ | ● | 20 | 210 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}, V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ $V_S = 3\text{V}, V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● ● | 66 62 | 80 75 | dB dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_S = 5\text{V}, V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ $V_S = 3\text{V}, V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● ● | 62 58 | 80 75 | dB dB |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.5\text{V}$ to $12\text{V}, V_{\text{CM}} = V_O = 0.5\text{V}$ | ● | 86 | 100 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = 2.5\text{V}$ to $12\text{V}, V_{\text{CM}} = V_O = 0.5\text{V}$ | ● | 80 | 100 | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 22 | 50 | mV |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | 45 | 80 | mV |
| | | $I_{\text{SINK}} = 2.5\text{mA}$ | ● | 110 | 220 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 20 | mV |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | 60 | 120 | mV |
| | | $I_{\text{SOURCE}} = 2.5\text{mA}$ | ● | 170 | 350 | mV |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ | ● | ± 5 | ± 15 | mA |
| | | $V_S = 3\text{V}$ | ● | ± 5 | ± 15 | mA |
| I_S | Supply Current per Amplifier | | ● | 2.4 | 3.0 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz |
| SR | Slew Rate (Note 8) | $V_S = 5\text{V}, A_V = -1, R_L = \text{Open}, V_O = 4\text{V}$ | ● | 2.0 | 3.6 | V/ μs |
| | | $V_S = 3\text{V}, A_V = -1, R_L = \text{Open}$ | ● | 1.7 | 3.2 | V/ μs |

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_{OUT} = 0\text{V}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|---|---|-----------|-----------|----------|------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | | 200 | 800 | μV |
| | | $V_{CM} = V^-$ | | 200 | 800 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^-$ to V^+ | | 150 | 650 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{CM} = V^+$, V^- (Note 5) | | 250 | 1400 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | 0 | 250 | 715 | nA |
| | | $V_{CM} = V^-$ | -715 | -250 | 0 | nA |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^-$ to V^+ | | 500 | 1430 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{CM} = V^+$ (Note 5) $V_{CM} = V^-$ (Note 5) | 0 -120 | 12 -12 | 120 0 | nA nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | | 6 | 70 | nA |
| | | $V_{CM} = V^-$ | | 6 | 70 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^-$ to V^+ | | 12 | 140 | nA |
| | Input Noise Voltage | 0.1Hz to 10Hz | | 400 | | nV _{p-p} |
| e_n | Input Noise Voltage Density | $f = 1\text{kHz}$ | | 12 | | nV/ $\sqrt{\text{Hz}}$ |
| i_n | Input Noise Current Density | $f = 1\text{kHz}$ | | 0.3 | | pA/ $\sqrt{\text{Hz}}$ |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.5\text{V}$ to 14.5V , $R_L = 10\text{k}$ | 1000 | 5200 | | V/mV |
| | | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | 500 | 2300 | | V/mV |
| | Channel Separation | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | 116 | 130 | | dB |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^-$ to V^+ | 93 | 106 | | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_{CM} = V^-$ to V^+ | 87 | 103 | | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | 89 | 110 | | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | 83 | 105 | | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | | 18 | 30 | mV |
| | | $I_{SINK} = 0.5\text{mA}$ | | 40 | 80 | mV |
| | | $I_{SINK} = 10\text{mA}$ | | 230 | 500 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | | 2.5 | 10 | mV |
| | | $I_{SOURCE} = 0.5\text{mA}$ | | 55 | 120 | mV |
| | | $I_{SOURCE} = 10\text{mA}$ | | 420 | 800 | mV |
| I_{SC} | Short-Circuit Current | | ± 15 | ± 30 | | mA |
| I_S | Supply Current per Amplifier | | | 1.8 | 2.5 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | 6.8 | 10.5 | | MHz |
| SR | Slew Rate | $A_V = -1$, $R_L = \text{Open}$, $V_O = \pm 10\text{V}$ Measure at $V_O = \pm 5\text{V}$ | 3.5 | 6 | | V/ μs |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the temperature range 0°C < T_A < 70°C. V_S = ±15V, V_{CM} = 0V, V_{OUT} = 0V, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------|---|---|--------|------------|--------------|--------------|
| V _{OS} | Input Offset Voltage | V _{CM} = V ⁺ | ● | 200 | 900 | μV |
| | | V _{CM} = V ⁻ + 0.1V | ● | 200 | 900 | μV |
| V _{OS} TC | Input Offset Voltage Drift (Note 3) | V _{CM} = V ⁺ | ● | 1.0 | 3.5 | μV/°C |
| | | | ● | 2.0 | 5.0 | μV/°C |
| ΔV _{OS} | Input Offset Voltage Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 200 | 750 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | V _{CM} = V ⁻ + 0.1V, V ⁺ (Note 5) | ● | 350 | 1500 | μV |
| I _B | Input Bias Current | V _{CM} = V ⁺ | ● | 0 | 300 | nA |
| | | V _{CM} = V ⁻ + 0.1V | ● | -875 | -300 | 0 |
| ΔI _B | Input Bias Current Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 600 | 1750 | nA |
| | Input Bias Current Match (Channel-to-Channel) | V _{CM} = V ⁺ (Note 5) V _{CM} = V ⁻ + 0.1V (Note 5) | ● ● | 0 -180 | 20 -20 | 180 0 |
| I _{OS} | Input Offset Current | V _{CM} = V ⁺ | ● | 15 | 90 | nA |
| | | V _{CM} = V ⁻ + 0.1V | ● | 15 | 90 | nA |
| ΔI _{OS} | Input Offset Current Shift | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 30 | 180 | nA |
| A _{VOL} | Large-Signal Voltage Gain | V _O = -14.5V to 14.5V, R _L = 10k V _O = -10V to 10V, R _L = 2k | ● ● | 900 400 | 5000 2000 | V/mV V/mV |
| | Channel Separation | V _O = -10V to 10V, R _L = 2k | ● | 112 | 125 | dB |
| CMRR | Common Mode Rejection Ratio | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 92 | 103 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | V _{CM} = V ⁻ + 0.1V to V ⁺ | ● | 86 | 103 | dB |
| PSRR | Power Supply Rejection Ratio | V _S = ±5V to ±15V | ● | 88 | 103 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | V _S = ±5V to ±15V | ● | 82 | 103 | dB |
| V _{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 18 | 40 | mV |
| | | I _{SINK} = 0.5mA | ● | 45 | 90 | mV |
| | | I _{SINK} = 10mA | ● | 270 | 520 | mV |
| V _{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 15 | mV |
| | | I _{SOURCE} = 0.5mA | ● | 60 | 120 | mV |
| | | I _{SOURCE} = 10mA | ● | 480 | 1000 | mV |
| I _{SC} | Short-Circuit Current | | ● | ±12 | ±28 | mA |
| I _S | Supply Current per Amplifier | | ● | 1.9 | 2.8 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 6.1 | 9 | MHz |
| SR | Slew Rate | A _V = -1, R _L = Open, V _O = ±10V Measured at V _O = ±5V | ● | 3.4 | 5.3 | V/μs |

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_{OUT} = 0\text{V}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|---|---|--------|------------|--------------|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | ● | 300 | 950 | μV |
| | | $V_{CM} = V^- + 0.1\text{V}$ | ● | 300 | 950 | μV |
| $V_{OS\ TC}$ | Input Offset Voltage Drift (Note 3) | | ● | 1.0 | 3.5 | $\mu\text{V}/^{\circ}\text{C}$ |
| | | $V_{CM} = V^+$ | ● | 2.0 | 5.0 | $\mu\text{V}/^{\circ}\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^- + 0.1\text{V}$ to V^+ | ● | 250 | 850 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{CM} = V^- + 0.1\text{V}$, V^+ (Note 5) | ● | 350 | 1800 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | ● | 0 | 350 | nA |
| | | $V_{CM} = V^- + 0.1\text{V}$ | ● | -1050 | -350 | 0 |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^- + 0.1\text{V}$ to V^+ | ● | 700 | 2100 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{CM} = V^+$ (Note 5) $V_{CM} = V^- + 0.1\text{V}$ (Note 5) | ● ● | 0 -200 | 20 -20 | 200 0 |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | ● | 15 | 115 | nA |
| | | $V_{CM} = V^- + 0.1\text{V}$ | ● | 15 | 115 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^- + 0.1\text{V}$ to V^+ | ● | 30 | 230 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.5\text{V}$ to 14.5V , $R_L = 10\text{k}$ $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | ● ● | 800 350 | 5000 2000 | V/mV V/mV |
| | Channel Separation | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | ● | 110 | 120 | dB |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^- + 0.1\text{V}$ to V^+ | ● | 90 | 101 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_{CM} = V^- + 0.1\text{V}$ to V^+ | ● | 86 | 100 | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 88 | 100 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 82 | 100 | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 25 | 50 | mV |
| | | $I_{SINK} = 0.5\text{mA}$ | ● | 50 | 100 | mV |
| | | $I_{SINK} = 10\text{mA}$ | ● | 275 | 520 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 15 | mV |
| | | $I_{SOURCE} = 0.5\text{mA}$ | ● | 65 | 120 | mV |
| | | $I_{SOURCE} = 10\text{mA}$ | ● | 500 | 1000 | mV |
| I_{SC} | Short-Circuit Current | | ● | ± 10 | ± 18 | mA |
| I_S | Supply Current per Amplifier | | ● | 2.0 | 3.0 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz |
| SR | Slew Rate | $A_V = -1$, $R_L = \text{Open}$, $V_O = \pm 10\text{V}$ Measure at $V_O = \pm 5\text{V}$ | ● | 3 | 4.75 | V/ μs |

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the temperature range $-40^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_{OUT} = 0\text{V}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|---|---|--------|-----------|-----------|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 350 | 1300 | μV |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | 350 | 1300 | μV |
| $V_{OS\ TC}$ | Input Offset Voltage Drift (Note 3) | | ● | 1.0 | | $\mu\text{V}/^{\circ}\text{C}$ |
| | | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 2.0 | | $\mu\text{V}/^{\circ}\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 250 | 1500 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{CM} = V^- + 0.5\text{V}$, $V^+ - 0.5\text{V}$ (Note 5) | ● | 400 | 2200 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 0 | 500 | nA |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | -1200 | -500 | 0 |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 1000 | 2400 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{CM} = V^+ - 0.5\text{V}$ (Note 5) $V_{CM} = V^- + 0.5\text{V}$ (Note 5) | ● ● | 0 -400 | 40 -40 | 400 0 |
| I_{OS} | Input Offset Current | $V_{CM} = V^+ - 0.5\text{V}$ | ● | 40 | 300 | nA |
| | | $V_{CM} = V^- + 0.5\text{V}$ | ● | 40 | 300 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 600 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.5\text{V}$ to 14.5V , $R_L = 10\text{k}$ | ● | 40 | 400 | V/mV |
| | Channel Separation | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | ● | 110 | 120 | dB |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 86 | 100 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_{CM} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 100 | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 88 | 100 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 80 | 100 | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 25 | 75 | mV |
| | | $I_{SINK} = 0.5\text{mA}$ | ● | 50 | 100 | mV |
| | | $I_{SINK} = 10\text{mA}$ | ● | 275 | 520 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 20 | mV |
| | | $I_{SOURCE} = 0.5\text{mA}$ | ● | 65 | 120 | mV |
| | | $I_{SOURCE} = 10\text{mA}$ | ● | 500 | 1400 | mV |
| I_{SC} | Short-Circuit Current | | ● | ± 7.5 | ± 12 | mA |
| I_S | Supply Current per Amplifier | | ● | 2.5 | 3.2 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz |
| SR | Slew Rate | $A_V = -1$, $R_L = \text{Open}$, $V_O = \pm 10\text{V}$ Measure at $V_O = \pm 5\text{V}$ | ● | 2.2 | 4.75 | V/ μs |

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range $-55^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $V_{\text{CM}} = 0\text{V}$, $V_{\text{OUT}} = 0\text{V}$, unless otherwise noted. (Note 4)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------|---|---|--------|-----------|-----------|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 350 | 1300 | μV |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | 350 | 1300 | μV |
| $V_{\text{OS TC}}$ | Input Offset Voltage Drift (Note 3) | | ● | 1.0 | | $\mu\text{V}/^{\circ}\text{C}$ |
| | | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 2.0 | | $\mu\text{V}/^{\circ}\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 250 | 1500 | μV |
| | Input Offset Voltage Match (Channel-to-Channel) | $V_{\text{CM}} = V^- + 0.5\text{V}$, $V^+ - 0.5\text{V}$ (Note 5) | ● | 400 | 2200 | μV |
| I_{B} | Input Bias Current | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 0 | 500 | nA |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | -1200 | -500 | 0 |
| ΔI_{B} | Input Bias Current Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 1000 | 2400 | nA |
| | Input Bias Current Match (Channel-to-Channel) | $V_{\text{CM}} = V^+ - 0.5\text{V}$ (Note 5) $V_{\text{CM}} = V^- + 0.5\text{V}$ (Note 5) | ● ● | 0 -400 | 40 -40 | 400 0 |
| I_{OS} | Input Offset Current | $V_{\text{CM}} = V^+ - 0.5\text{V}$ | ● | 40 | 300 | nA |
| | | $V_{\text{CM}} = V^- + 0.5\text{V}$ | ● | 40 | 300 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 600 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_{\text{O}} = -14.5\text{V}$ to 14.5V , $R_{\text{L}} = 10\text{k}$ | ● | 40 | 400 | V/mV |
| | Channel Separation | $V_{\text{O}} = -10\text{V}$ to 10V , $R_{\text{L}} = 2\text{k}$ | ● | 110 | 120 | dB |
| CMRR | Common Mode Rejection Ratio | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 86 | 100 | dB |
| | CMRR Match (Channel-to-Channel) (Note 5) | $V_{\text{CM}} = V^- + 0.5\text{V}$ to $V^+ - 0.5\text{V}$ | ● | 80 | 100 | dB |
| PSRR | Power Supply Rejection Ratio | $V_{\text{S}} = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 88 | 100 | dB |
| | PSRR Match (Channel-to-Channel) (Note 5) | $V_{\text{S}} = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 80 | 100 | dB |
| V_{OL} | Output Voltage Swing (Low) (Note 6) | No Load | ● | 25 | 75 | mV |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | 50 | 100 | mV |
| | | $I_{\text{SINK}} = 10\text{mA}$ | ● | 275 | 520 | mV |
| V_{OH} | Output Voltage Swing (High) (Note 6) | No Load | ● | 3.5 | 20 | mV |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | 65 | 120 | mV |
| | | $I_{\text{SOURCE}} = 10\text{mA}$ | ● | 500 | 1400 | mV |
| I_{SC} | Short-Circuit Current | | ● | ± 7.5 | ± 12 | mA |
| I_{S} | Supply Current per Amplifier | | ● | 2.5 | 3.2 | mA |
| GBW | Gain-Bandwidth Product (Note 7) | | ● | 5.8 | 8.5 | MHz |
| SR | Slew Rate | $A_{\text{V}} = -1$, $R_{\text{L}} = \text{Open}$, $V_{\text{O}} = \pm 10\text{V}$ Measure at $V_{\text{O}} = \pm 5\text{V}$ | ● | 2.2 | 4.75 | V/ μs |

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.

Note 3: This parameter is not 100% tested.

Note 4: The LT1498C/LT1499C are guaranteed to meet specified performance from 0°C to 70°C . The LT1498C/LT1499C are designed, characterized and expected to meet specified performance from -40°C to 85°C but are not tested or QA sampled at these temperatures. The LT1498I/LT1499I are guaranteed to meet specified performance from -40°C to 85°C . The LT1498H/LT1499H are guaranteed to meet specified performance from -40°C to 125°C . The LT1498MP is guaranteed to meet specified performance from -55°C to 125°C .

Note 5: Matching parameters are the difference between amplifiers A and D and between B and C on the LT1499; between the two amplifiers on the LT1498.

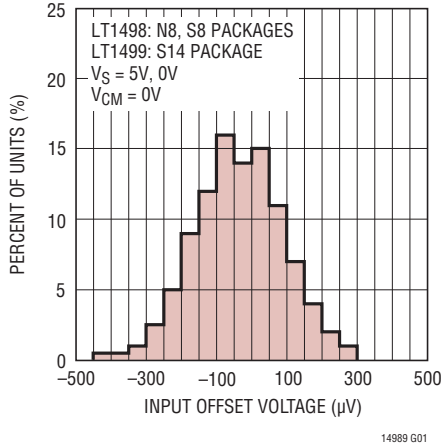
Note 6: Output voltage swings are measured between the output and power supply rails.

Note 7: $V_{\text{S}} = 3\text{V}$, $V_{\text{S}} = \pm 15\text{V}$ GBW limit guaranteed by correlation to 5V tests.

Note 8: $V_{\text{S}} = 3\text{V}$, $V_{\text{S}} = 5\text{V}$ slew rate limit guaranteed by correlation to $\pm 15\text{V}$ tests.

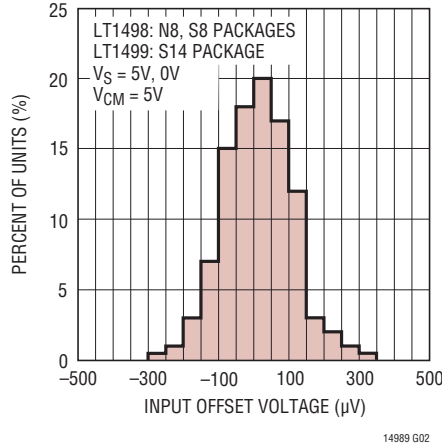
TYPICAL PERFORMANCE CHARACTERISTICS

V_{OS} Distribution, $V_{CM} = 0V$ (PNP Stage)



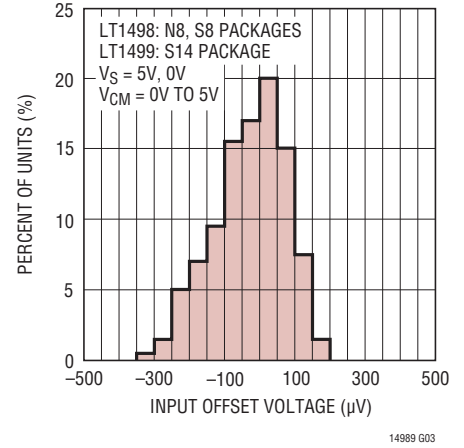
14989 G01

V_{OS} Distribution $V_{CM} = 5V$ (NPN Stage)



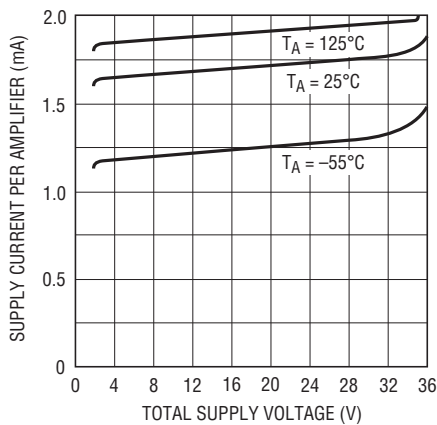
14989 G02

ΔV_{OS} Shift for $V_{CM} = 0V$ to $5V$



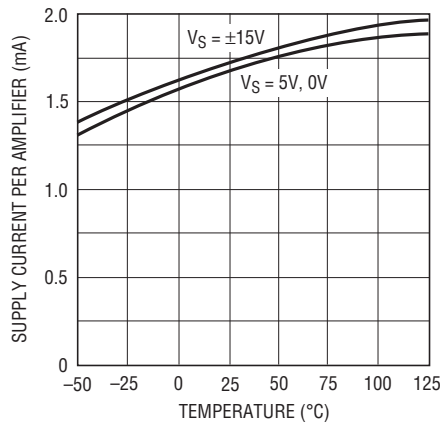
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Supply Current vs Supply Voltage



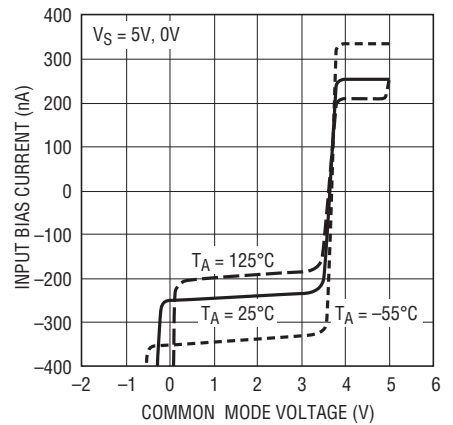
14989 G04

Supply Current vs Temperature



14989 G05

Input Bias Current vs Common Mode Voltage



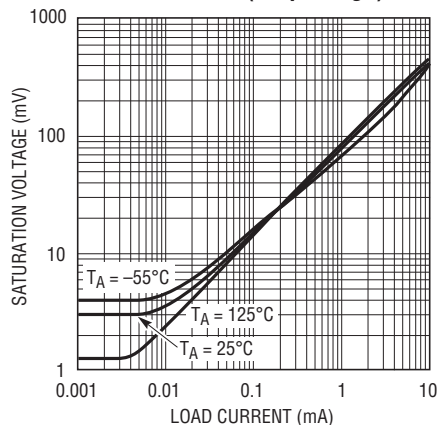
14989 G06

Input Bias Current vs Temperature



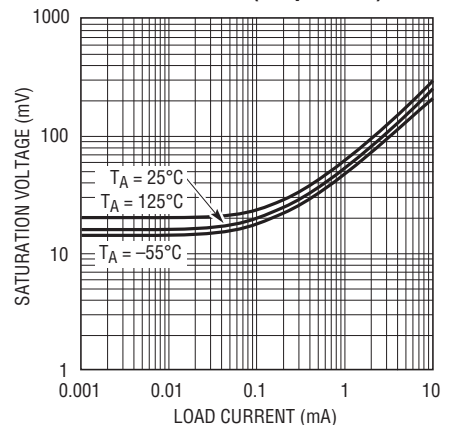
14989 G07

Output Saturation Voltage vs Load Current (Output High)



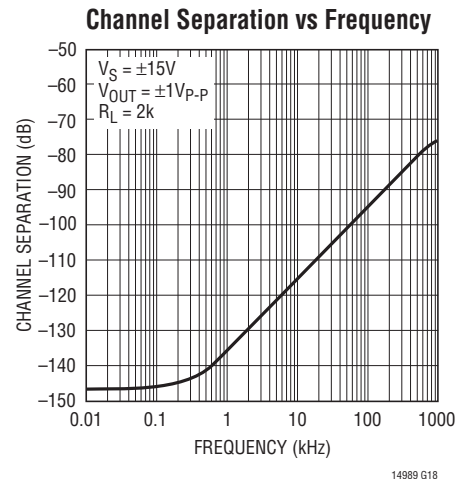
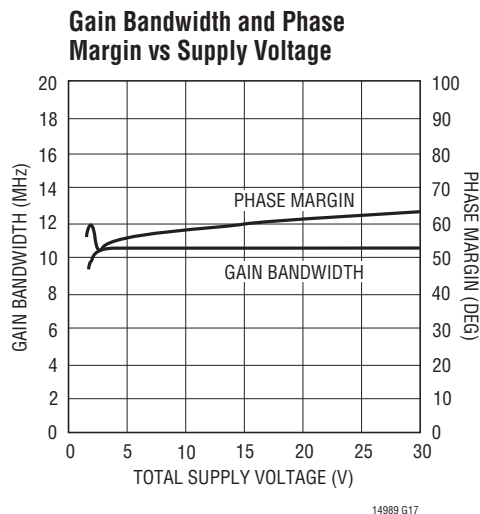
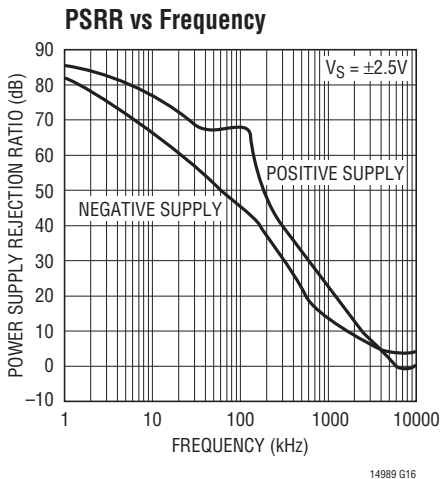
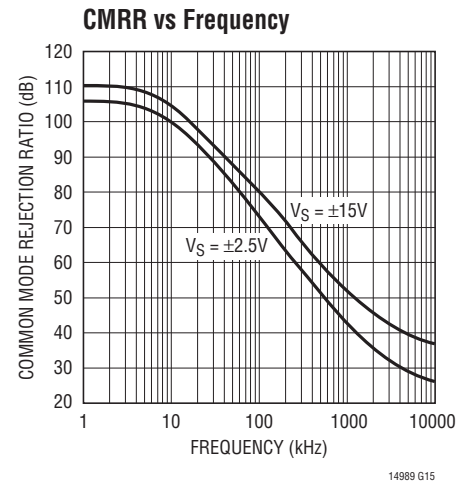
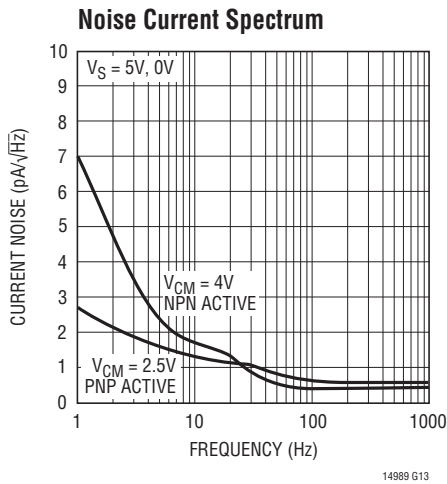
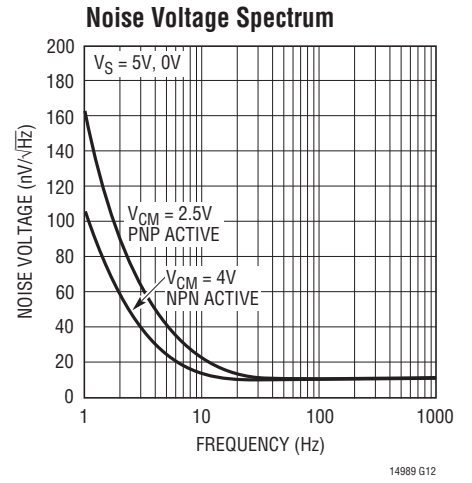
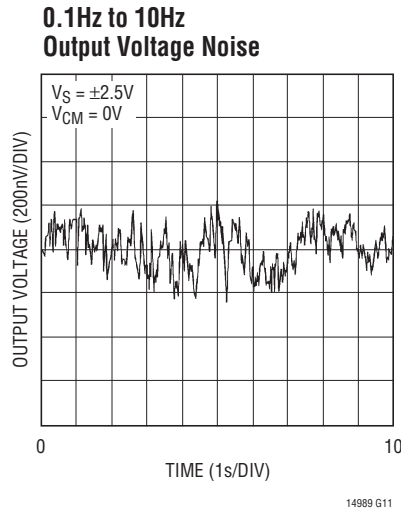
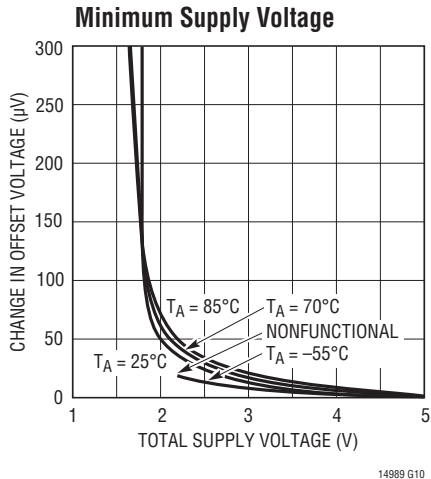
14989 G08

Output Saturation Voltage vs Load Current (Output Low)



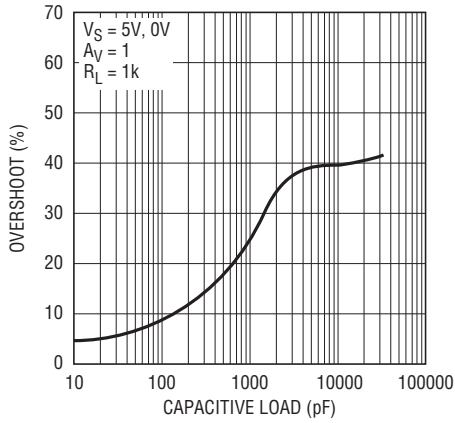
14989 G09

TYPICAL PERFORMANCE CHARACTERISTICS



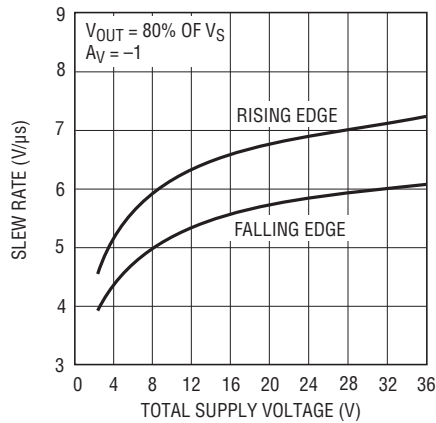
TYPICAL PERFORMANCE CHARACTERISTICS

Capacitive Load Handling



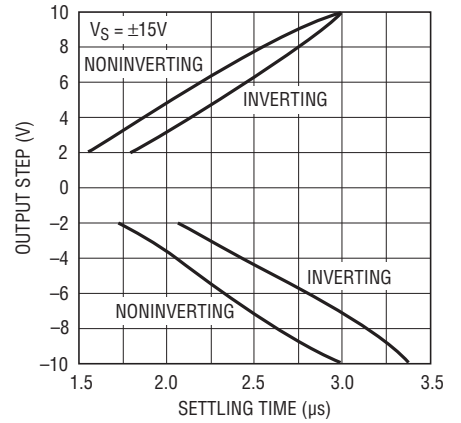
14989 G19

Slew Rate vs Supply Voltage



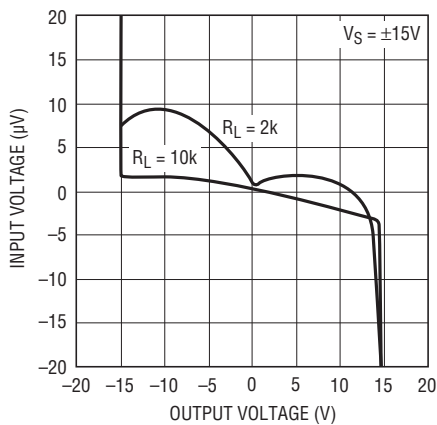
14989 G20

Output Step vs Settling Time to 0.01%



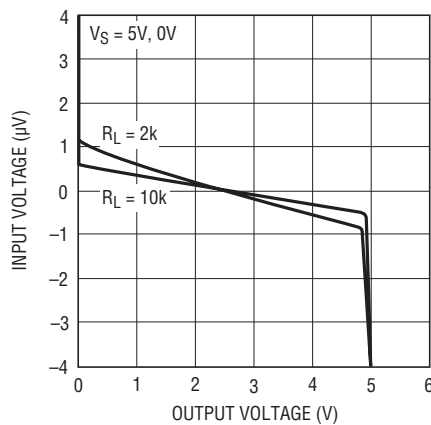
14989 G21

Open-Loop Gain



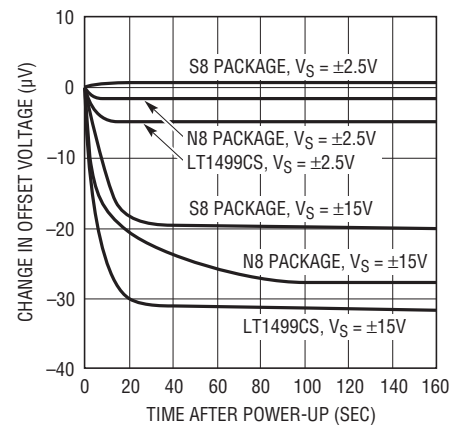
14989 G22

Open-Loop Gain



14989 G23

Warm-Up Drift vs Time



14989 G24

Total Harmonic Distortion + Noise vs Peak-to-Peak Voltage



14989 G25

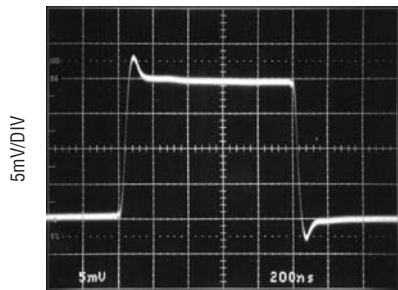
Total Harmonic Distortion + Noise vs Frequency



14989 G26

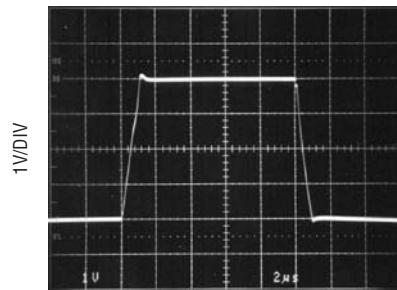
TYPICAL PERFORMANCE CHARACTERISTICS

5V Small-Signal Response



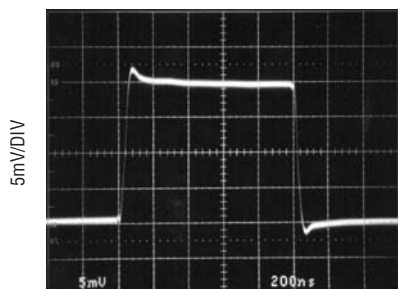
$V_S = 5V$ 200ns/DIV 14989 G27
 $A_V = 1$
 $V_{IN} = 20mV_{p-p}$ AT 50kHz
 $R_L = 1k$

5V Large-Signal Response



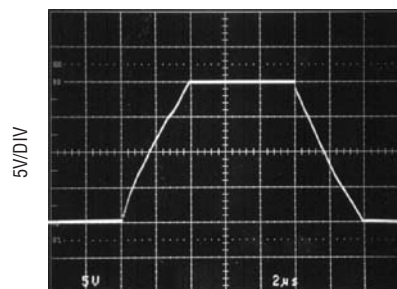
$V_S = 5V$ 2µs/DIV 14989 G28
 $A_V = 1$
 $V_{IN} = 4V_{p-p}$ AT 10kHz
 $R_L = 1k$

±15V Small-Signal Response



$V_S = \pm 15V$ 200ns/DIV 14989 G29
 $A_V = 1$
 $V_{IN} = 20mV_{p-p}$ AT 50kHz
 $R_L = 1k$

±15V Large-Signal Response



$V_S = \pm 15V$ 2µs/DIV 14989 G30
 $A_V = 1$
 $V_{IN} = 20V_{p-p}$ AT 10kHz
 $R_L = 1k$

APPLICATIONS INFORMATION

Rail-to-Rail Input and Output

The LT1498/LT1499 are fully functional for an input and output signal range from the negative supply to the positive supply. Figure 1 shows a simplified schematic of the amplifier. The input stage consists of two differential amplifiers, a PNP stage (Q1/Q2) and an NPN stage (Q3/Q4) which are active over different ranges of input common mode voltage. A complementary common emitter output stage (Q14/Q15) is employed allowing the output to swing from rail-to-rail. The devices are fabricated on Linear Technology's proprietary complementary bipolar process to ensure very similar DC and AC characteristics for the output devices (Q14/Q15).

The PNP differential input pair is active for input common mode voltages, V_{CM} , between the negative supply to approximately 1.3V below the positive supply. As V_{CM} moves further toward the positive supply, the transistor (Q5) will steer the tail current, I_1 , to the current mirror (Q6/Q7) activating the NPN differential pair, and the PNP differential pair becomes inactive for the rest of the input common mode range up to the positive supply.

The output is configured with a pair of complementary common emitter stages that enables the output to swing from rail to rail. Capacitors (C1 and C2) form local feedback loops that lower the output impedance at high frequencies.

Input Offset Voltage

The offset voltage changes depending upon which input stage is active. The input offsets are random, but are trimmed to less than $475\mu\text{V}$. To maintain the precision characteristics of the amplifier, the change of V_{OS} over the entire input common mode range (CMRR) is guaranteed to be less than $425\mu\text{V}$ on a single 5V supply.

Input Bias Current

The input bias current polarity also depends on the input common mode voltage, as described in the previous section. When the PNP differential pair is active, the input bias currents flow out of the input pins; they flow in opposite direction when the NPN input stage is active. The offset error due to input bias current can be minimized by equalizing the noninverting and inverting input source impedances. This will reduce the error since the input offset currents are much less than the input bias currents.



Figure 1. LT1498 Simplified Schematic Diagram

APPLICATIONS INFORMATION

Overdrive Protection

To prevent the output from reversing polarity when the input voltage exceeds the power supplies, two pair of crossing diodes D1 to D4 are employed. When the input voltage exceeds either power supply by approximately 700mV, D1/D2 or D3/D4 will turn on, forcing the output to the proper polarity. For the phase reversal protection to work properly, the input current must be less than 5mA. If the amplifier is to be severely overdriven, an external resistor should be used to limit the overdrive current.

Furthermore, the LT1498/LT1499's input stages are protected by a pair of back-to-back diodes, D5/D6. When a differential voltage of more than 0.7V is applied to the inputs, these diodes will turn on, preventing the Zener breakdown of the input transistors. The current in D5/D6 should be limited to less than 10mA. Internal resistors R6 and R7 (700Ω total) limit the input current for differential input signals of 7V or less. For larger input levels, a resistor in series with either or both inputs should be used to limit the current. Worst-case differential input voltage usually occurs when the output is shorted to ground. In addition, the amplifier is protected against ESD strikes up to 3kV on all pins.

Capacitive Load

The LT1498/LT1499 are designed for ease of use. The amplifier can drive a capacitive load of more than 10nF without oscillation at unity gain. When driving a heavy capacitive load, the bandwidth is reduced to maintain stability. Figures 2a and 2b illustrate the stability of the device for small-signal and large-signal conditions with capacitive loads. Both the small-signal and large-signal transient response with a 10nF capacitive load are well behaved.

Feedback Components

To minimize the loading effect of feedback, it is possible to use the high value feedback resistors to set the gain. However, care must be taken to insure that the pole formed by the feedback resistors and the total input capacitance at the inverting input does not degrade the stability of the amplifier. For instance, the LT1498/LT1499 in a noninverting gain of 2, set with two 30k resistors, will probably oscillate with 10pF total input capacitance (5pF input capacitance + 5pF board capacitance). The amplifier has a 2.5MHz crossing frequency and a 60° phase margin at 6dB of gain. The feedback resistors and the total input capacitance create a pole at 1.06MHz that induces 67° of phase shift at 2.5MHz! The solution is simple, either lower the value of the resistors or add a feedback capacitor of 10pF or more.

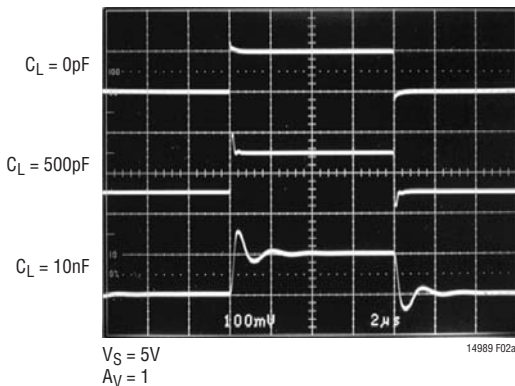


Figure 2a. LT1498 Small-Signal Response

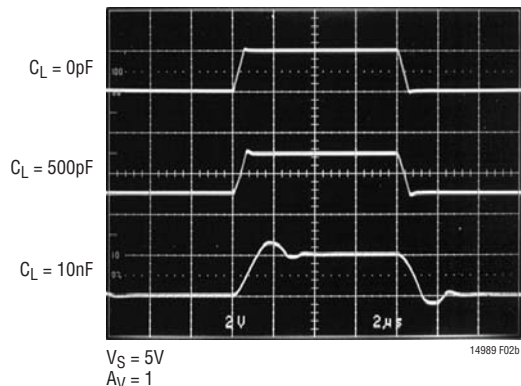
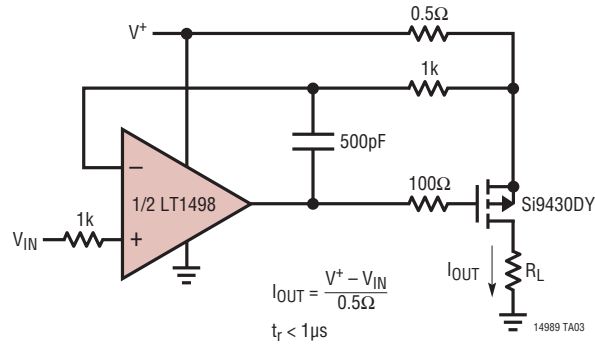


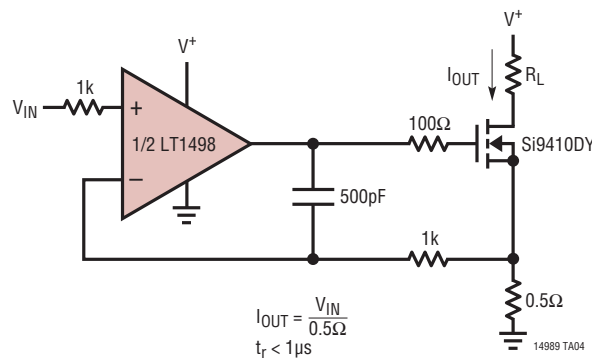
Figure 2b. LT1498 Large-Signal Response

TYPICAL APPLICATIONS

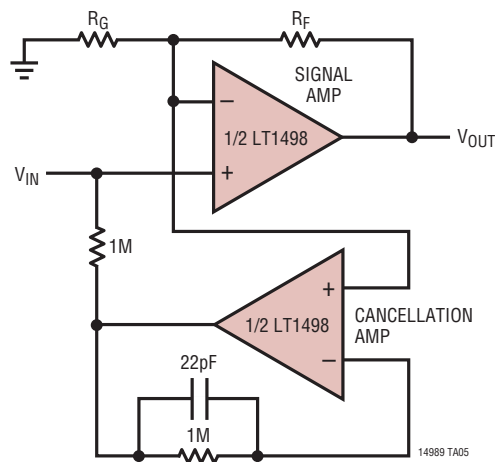
1A Voltage Controlled Current Source



1A Voltage Controlled Current Sink



Input Bias Current Cancellation



INPUT BIAS CURRENT LESS THAN 50nA
FOR $500mV \leq V_{IN} \leq (V^+ - 500mV)$

PACKAGE DESCRIPTION

N8 Package
8-Lead PDIP (Narrow .300 Inch)
 (Reference LTC DWG # 05-08-1510)

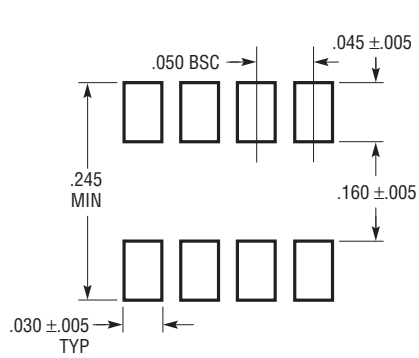


NOTE:
 1. DIMENSIONS ARE $\frac{\text{INCHES}}{\text{MILLIMETERS}}$
 *THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
 MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

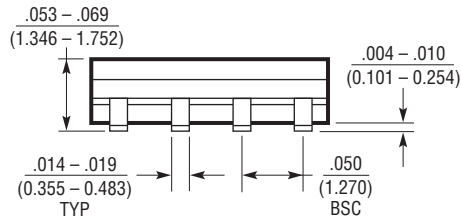
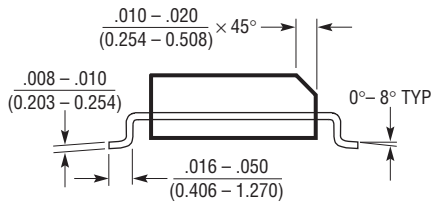
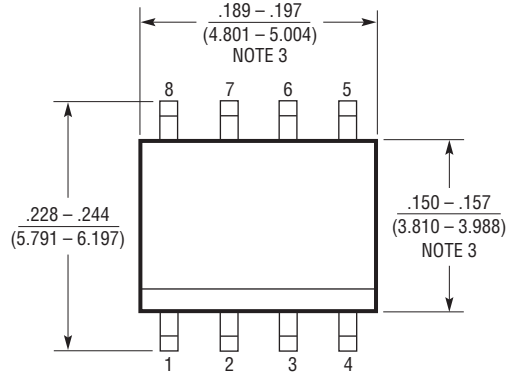
N8 1002

PACKAGE DESCRIPTION

S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



RECOMMENDED SOLDER PAD LAYOUT

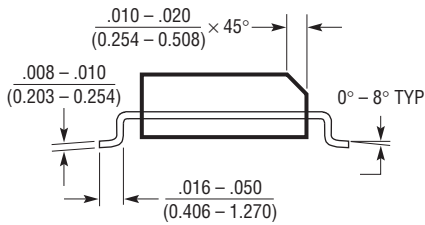
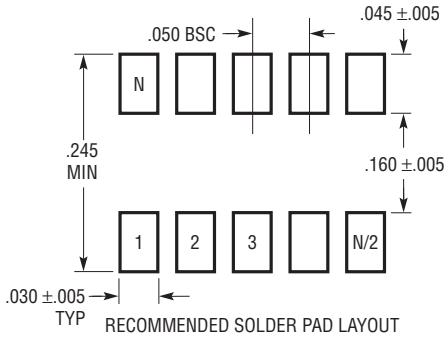


- NOTE:
1. DIMENSIONS IN $\frac{\text{INCHES}}{\text{MILLIMETERS}}$
2. DRAWING NOT TO SCALE
3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED $.006"$ (0.15mm)

S08 0303

PACKAGE DESCRIPTION

S Package
14-Lead Plastic Small Outline (Narrow .150 Inch)
 (Reference LTC DWG # 05-08-1610)



- NOTE:
1. DIMENSIONS IN $\frac{\text{INCHES}}{\text{MILLIMETERS}}$
 2. DRAWING NOT TO SCALE
 3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm)

S14 0502

REVISION HISTORY (Revision history begins at Rev E)

| REV | DATE | DESCRIPTION | PAGE NUMBER |
|-----|-------|---|-------------|
| E | 10/09 | Edit in Absolute Maximum Ratings | 2 |
| F | 01/10 | Added LT1498H/LT1499H (H-Grade) Parts. Reflected throughout the data sheet. | 2-24 |
| G | 03/10 | Updated Part Markings in Order Information Section | 2 |
| | | Updated Conditions for A_{VOL} in Electrical Characteristics Section | 6, 7 |

TYPICAL APPLICATION

Bidirectional Current Sensor

A bidirectional current sensor for battery-powered systems is shown in Figure 3. Two outputs are provided: one proportional to charge current, the other proportional to discharge current. The circuit takes advantage of the LT1498's rail-to-rail input range and its output phase reversal protection. During the charge cycle, the op amp

A1 forces a voltage equal to $(I_L)(R_{SENSE})$ across R_A . This voltage is then amplified at the Charge Out by the ratio of R_B over R_A . In this mode, the output of A2 remains high, keeping Q2 off and the Discharge Out low, even though the (+) input of A2 exceeds the positive power supply. During the discharge cycle, A2 and Q2 are active and the operation is similar to the charge cycle.



Figure 3. Bidirectional Current Sensor

RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|---------------|--|---|
| LTC®1152 | Rail-to-Rail Input and Output, Zero-Drift Op Amp | High DC Accuracy, 10μV $V_{OS(MAX)}$, 100nV/°C Drift, 1MHz GBW, 1V/μs Slew Rate, Max Supply Current 2.2mA |
| LT1211/LT1212 | Dual/Quad 14MHz, 7V/μs, Single Supply Precision Op Amps | Input Common Mode Includes Ground, 275μV $V_{OS(MAX)}$, 6μV/°C Max Drift, Max Supply Current 1.8mA per Op Amp |
| LT1213/LT1214 | Dual/Quad 28MHz, 12V/μs, Single Supply Precision Op Amps | Input Common Mode Includes Ground, 275μV $V_{OS(MAX)}$, 6μV/°C Max Drift, Max Supply Current 3.5mA per Op Amp |
| LT1215/LT1216 | Dual/Quad 23MHz, 50V/μs, Single Supply Precision Op Amps | Input Common Mode Includes Ground, 450μV $V_{OS(MAX)}$, Max Supply Current 6.6mA per Op Amp |
| LT1366/LT1367 | Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps | 475μV $V_{OS(MAX)}$, 400kHz GBW, 0.13V/μs Slew Rate, Max Supply Current 520μA per Op Amp |
| LT1490/LT1491 | Dual/Quad Micropower, Rail-to-Rail Input and Output Op Amps | Max Supply Current 50μA per Op Amp, 200kHz GBW, 0.07V/μs Slew Rate, Operates with Inputs 44V Above V^- Independent of V^+ |
| LT1884/LT1885 | Dual/Quad, Rail-to-Rail Output Picoamp Input Precision Op Amps | $I_{CC} = 650μA, V_{OS} < 50μV, I_B < 400pA$ |



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- Поставка более 17-ти миллионов наименований электронных компонентов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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